NSN 5961-01-156-8147

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-156-8147 **Inclosure Material:** Metal **Overall Length:** Between 1.553 inches and 1.573 inches **Overall Height:** 0.762 inches **Overall Width:** 1.050 inches **End Application:** 1440-01-207-3002 **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-3 **Mounting Method:** Unthreaded hole **Features Provided:** Electrostatic sensitive and hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 350.0 drain to source voltage and 20.0 gate to source voltage **Current Rating Per Characteristic:** 8.00 amperes off-state current, peak and 4.00 amperes dark current **Power Rating Per Characteristic:** 75.0 watts total device dissipation **Test Data Document:** 18876-13153395 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**